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Subs	stitute for form 1449A	√PTO		Complete if Known				
				Application Number	10/627,218			
1	INFORMATION	DISCL	OSURE	Filing Date	July 25, 2003			
	STATEMENT B	Y APPI	_ICANT	First Named Inventor	Yeo, et al.			
				Art Unit	Unknown			
	(use as many shee	ets as nec	essary)	Examiner Name	Unknown			
Sheet	1 1	of	1	Attorney Docket Number	TSM03-0556			

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Examiner	Cita	Document Number	Publication Date	Name of Patentee or	Pages, Columns, Lines, Where Relevant Passages or Relevan Figures Appear				
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	Cite No.1	Country Code ³ - Number ⁴ - Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document					
DK	Н	WO 03/017336 A2	02-27-2003	Amberwave Systems Corporation					
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OTHER PRIOR ART NON PATENT LITERATURE DOCUMENTS							
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Examiner Signature	(7	MA		 Date Considered	RICH	<u> </u>	

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